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# RENESAS TECHNICAL UPDATE

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Product Category	MPU & MCU	Document No.		TN-V85-A031A/E		1.00		
Title	Restriction of Multiplex bus cycle.		Information Category	I Lechnical Notification				
	V850E2/FL4	Lot No.					of	
Applicable Product		ALL lots	Reference Document	User's Manual a applicable product	nd Data	sheet		

This document describes restriction items of user's manual and datasheet about external memory access timing (MEMCOCLK asynchronous/synchronous timing) as below.

#### Restriction

(1) Added prohibited item at the MEMC0CLK synchronous

The setting of WAIT=0 is prohibited at the external memory access of MEMC0CLK synchronous.

According to this change, data input setup time (from MEMC0CLK (r)) is changed for "10+1T" at the external memory access of MEMC0CLK synchronous. Please refer to table-1, 2.

(2) Changed MEMC0WAIT hold time at the MEMC0CLK asynchronous

Minimum value of MEMC0WAIT hold time of external memory access "tHSTWT1" and "tHSTWT2" are changed.

Please refer to the table-3.



#### ■ Modifications of manual

# Restriction (1)

On the User's Manual Chapter 4.3.4 [DWC0, DWC1 registers content], "No data wait" is prohibited as below.

# Before correction

DWn3	DWn2	DWn1	DWn0	Number of data wait states
0	0	0	0	No data wait

#### After correction

DWn3	DWn2	DWn1	DWn0	Number of data wait states
0	0	0	0	Prohibited

Table-1 DWC0, DWC1 registers content

MEMC0CLK synchronous timing of datasheet is changed as below.

### Before correction

Parameter	Symbol		Condition	MIN.	TYP.	MAX.	Unit
Data input setup time	tsidk	<22>		10			ns
(from MEMC0CLK (r))	COIDIC						

# After correction

Parameter	Symbol		Condition	MIN.	TYP.	MAX.	Unit
Data input setup time	tsidk	<22>		10 + 1T			ns
(from MEMC0CLK (r))	COIDK						

Table-2 MEMC0CLK synchronous timing

### (2) About limitation item of 2.

MEMC0CLK asynchronous timing of datasheet is changed as below.

### Before correction

Parameter	Symb	ol	Condit ion	MIN.	TYP.	MAX.	Unit
MEMC0WAITZ hold time from MEMC0ASTBZ (f)	t <sub>HSTWT1</sub>	<16>	w ≧ 1	(w + AHW)T - (2HEAPCLK + 20)			ns
	tнsтwт2	<17>	w ≧ 1	(1 + w + AHW)T - (2HEAPCLK + 20)			ns

### After correction

Parameter	Symbol		Condit ion	MIN.	TYP.	MAX.	Unit
MEMCOWAITZ hold time from MEMCOASTBZ (f)	<b>t</b> HSTWT1	<16>	w ≧ 1	(w + AHW)T - (2HEAPCLK + <b>7.5</b> )			ns
	t <sub>HSTWT2</sub>	<17>	w ≧ 1	(1 + w + AHW)T - (2HEAPCLK + 7.5)			ns

Table-3 MEMC0CLK asynchronous timing